

Features

Low Gate Charge
High Power and current handling capability
Lead free product is acquired

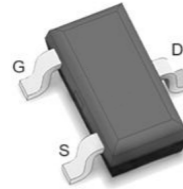
V_{DS} 20 V
 I_D 2.3 A
 $R_{DS(ON)}$ 45 m Ω

A2SHB

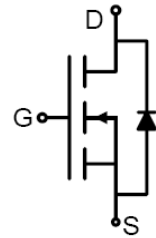
Applications

PWM Applications
Load Switch
Power Management

SOT-523 top view



Equivalent Circuit



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Limit	Unit
V_{DS}	Drain-Source Voltage ($V_{GS}=0V$)	20	V
V_{GS}	Gate-Source Voltage ($V_{DS}=0V$)	± 12	V
I_D	Drain Current-Continuous($T_A=25^\circ\text{C}$)	2.3	A
	Drain Current-Continuous($T_A=100^\circ\text{C}$)	2	A
$I_{DM (pulse)}$	Drain Current-Continuous@ Current-Pulsed (Note 1)	12.4	A
P_D	Maximum Power Dissipation($T_A=25^\circ\text{C}$)	0.96	W
	Maximum Power Dissipation($T_A=100^\circ\text{C}$)	0.4	W
E_{AS}	Avalanche energy (Note 2)	4	mJ
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 To 150	$^\circ\text{C}$

Table 2. Thermal Characteristic

Symbol	Parameter	Typ	Max	Unit
$R_{\theta JA}$	Thermal Resistance, Junction-to- Ambient		140	$^\circ\text{C}/\text{W}$

Electrical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
On/Off States						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	20			V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=20V, V_{GS}=0V, T_J=25^\circ\text{C}$			1	μA
		$V_{DS}=20V, V_{GS}=0V, T_J=125^\circ\text{C}$			100	μA
I_{GSS}	Gate-Body Leakage Current	$V_{GS}=\pm 12V, V_{DS}=0V$			± 100	μA
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu A$	0.45		1	V
g_{FS}	Forward Transconductance	$V_{DS}=4.5V, I_D=1.5A$		5.2		S
$R_{DS(ON)}$	Drain-Source On-State Resistance	$V_{GS}=4.5V, I_D=1.5A, T_J=25^\circ\text{C}$		45	55	$m\Omega$
$R_{DS(ON)}$	Drain-Source On-State Resistance	$V_{GS}=2.5V, I_D=1A, T_J=25^\circ\text{C}$		55	68	$m\Omega$
Dynamic Characteristics						
C_{iss}	Input Capacitance	$V_{DS}=10V, V_{GS}=0V, f=1.0KHz$		186		pF
C_{oss}	Output Capacitance			30		pF
C_{rss}	Reverse Transfer Capacitance			23		pF
R_g	Gate resistance	$V_{GS}=0V, V_{DS}=0V, f=1.0MHz$		9.3		Ω
Switching Parameters						
$t_{d(on)}$	Turn-on Delay Time	$V_{GS}=4.5V, V_{DS}=10V, R_L=6.7\Omega, R_{GEN}=3\Omega$		3		nS
t_r	Turn-on Rise Time			11		nS
$t_{d(off)}$	Turn-Off Delay Time			20		nS
t_f	Turn-Off Fall Time			8		nS
Q_g	Total Gate Charge	$V_{GS}=4.5V, V_{DS}=10V, I_D=1.5A$		3		nC
Q_{gs}	Gate-Source Charge			0.5		nC
Q_{gd}	Gate-Drain Charge			0.7		nC
Source-Drain Diode Characteristics						
I_{SD}	Source-Drain Current (Body Diode)				2.3	A
V_{SD}	Forward on Voltage (Note 3)	$V_{GS}=0V, I_S=1.5A$			1.2	V
t_{rr}	Reverse Recovery Time	$I_F=1.5A, dI/dt=100A/\mu s$		4.3		ns
Q_{rr}	Reverse Recovery Charge	$I_F=1.5A, dI/dt=100A/\mu s$		0.6		nC

Notes 1.Repetitive Rating: Pulse width limited by maximum junction temperature.

Notes 2. E_{AS} condition: $T_J=25^\circ\text{C}, V_{DD}=10V, V_G=10V, R_G=25\Omega, L=0.5mH$.

Notes 3.Repetitive Rating: Pulse width limited by maximum junction temperature.

RATING AND CHARACTERISTIC CURVES

Figure 1. Output Characteristics

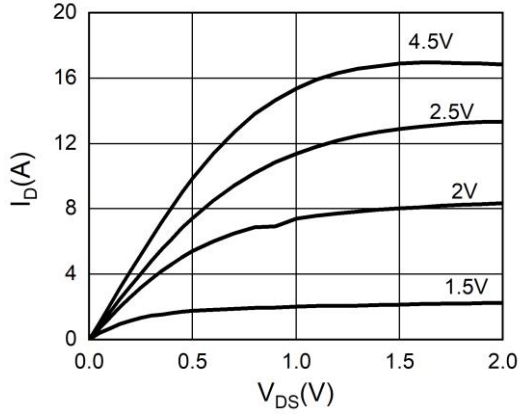


Figure 2. Transfer Characteristics

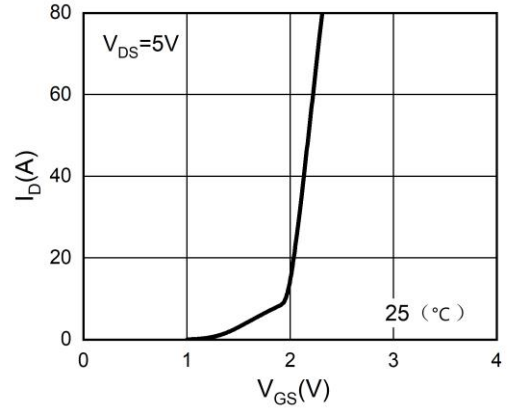


Figure 3. Power Dissipation

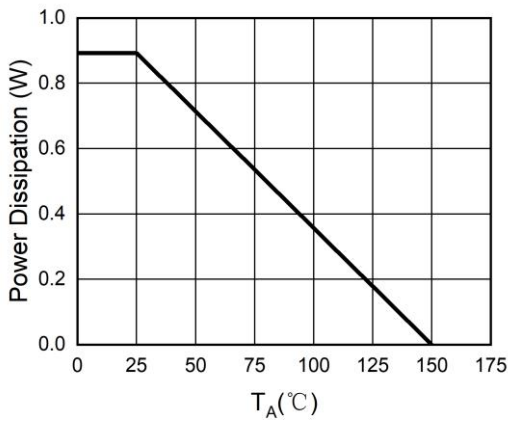


Figure 4. Drain Current

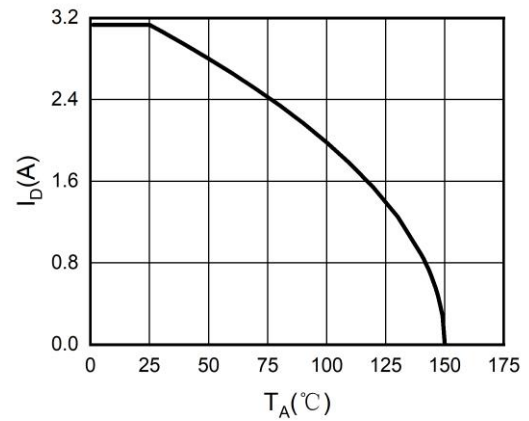


Figure 5. BV_{DSS} vs Junction Temperature

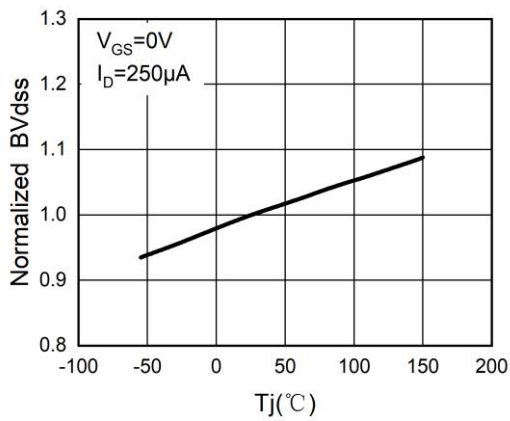
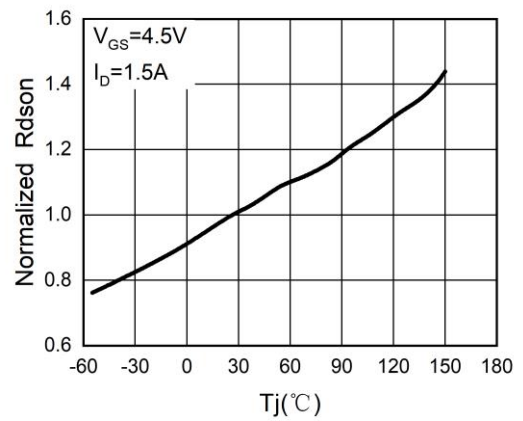


Figure 6. $R_{DS(ON)}$ vs Junction Temperature



RATING AND CHARACTERISTIC CURVES

Figure 7. Gate Charge Waveforms

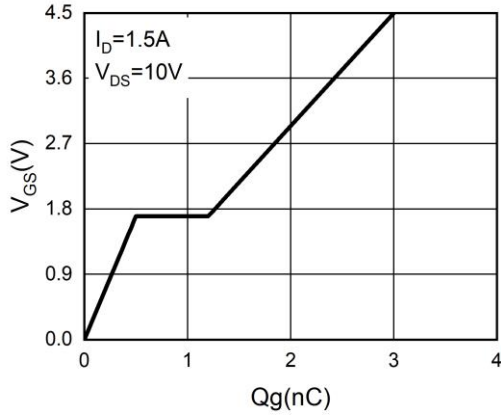


Figure 8. Capacitance

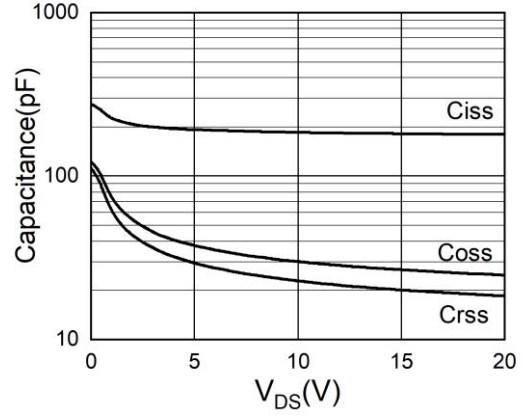


Figure 9. Body-Diode Characteristics

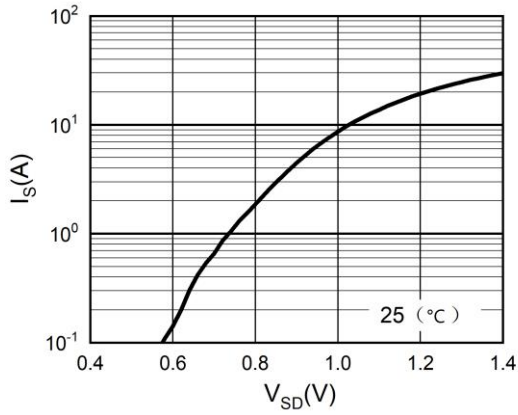
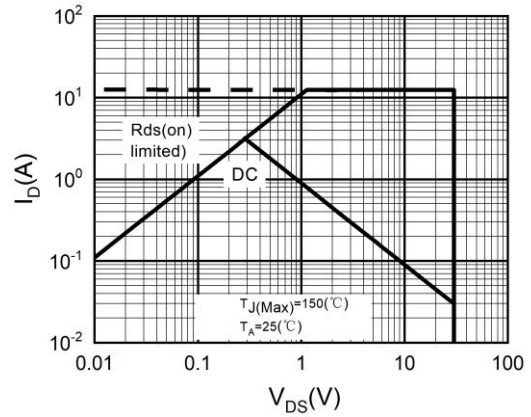


Figure 10. Maximum Safe Operating Area



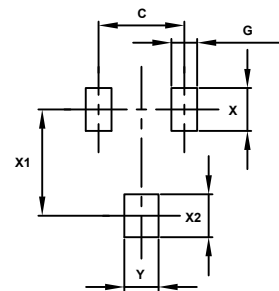
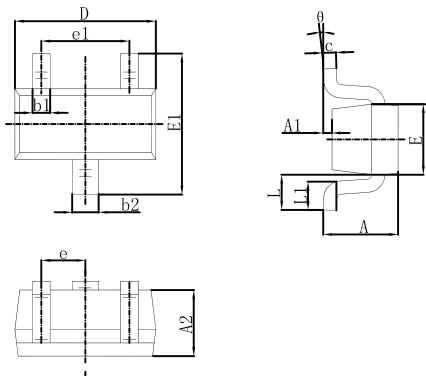
Soldering parameters

Reflow Condition		Pb-Free assembly (see as below)
Pre Heat	-Temperature Min ($T_{s(min)}$)	+150 °C
	-Temperature Max($T_{s(max)}$)	+200 °C
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquid us Temp (T_L) to peak)		3 °C/sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3 °C/sec. Max
Reflow	-Temperature(T_L)(Liquid us)	+217 °C
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_P)		+260(+0/-5) °C
Time within 5 °C of actual Peak Temp (t_p)		30 secs. Max
Ramp-down Rate		6 °C/sec. Max
Time 25 °C to Peak Temp (T_P)		8 min. Max
Do not exceed		+260 °C



Package Dimensions & Suggested Pad Layout

SOT-523



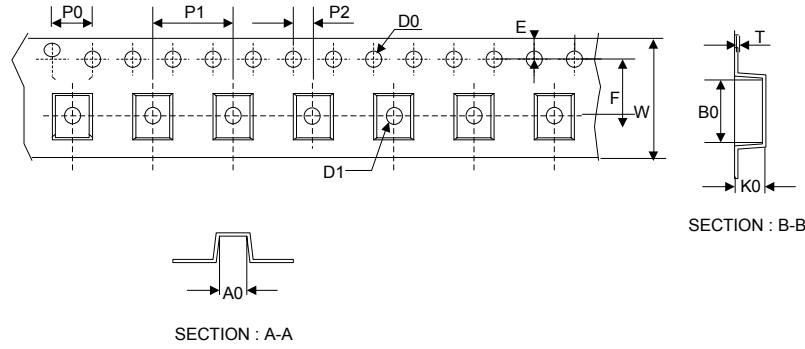
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
c	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
e	0.500 TYP.		0.020 TYP.	
e1	0.900	1.100	0.035	0.043
L	0.400 REF.		0.016 REF.	
L1	0.260	0.460	0.010	0.018
theta	0°	8°	0°	8°

Dimensions	Value (in mm)
C	1.00
G	0.45
X	0.70
X1	1.40
X2	0.70
Y	0.60

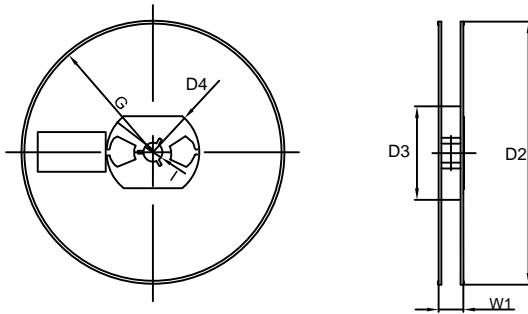
Dimensions in inches and (millimeters)

Tape & reel specification

Tape



7" Reel



Symbol	Dimension (mm)
P0	4.00±0.20
P1	4.00±0.20
P2	2.00±0.20
D0	1.55±0.20
D1	0.65±0.20
E	1.55±0.25
F	3.60±0.20
W	8.00±0.20
A0	2.10±0.20
B0	2.20±0.20
K0	1.10±0.20
T	0.20±0.20
D2	177.0±5.0
D3	55Min.
D4	R24.6±2.0
G	R82.0±2.0
I	13.0±2.0
W1	10.20±3.0

Quantity: 3000PCS